

Wavefront detection & modulation

Detection

- Types of photodetectors
- Digital imaging
- Color

Modulation

- Photographic film
- Spatial light modulators
- Binary optics

Imaging: detection of light

- a) photothermal (pyroelectric)
- b) photoconductivity

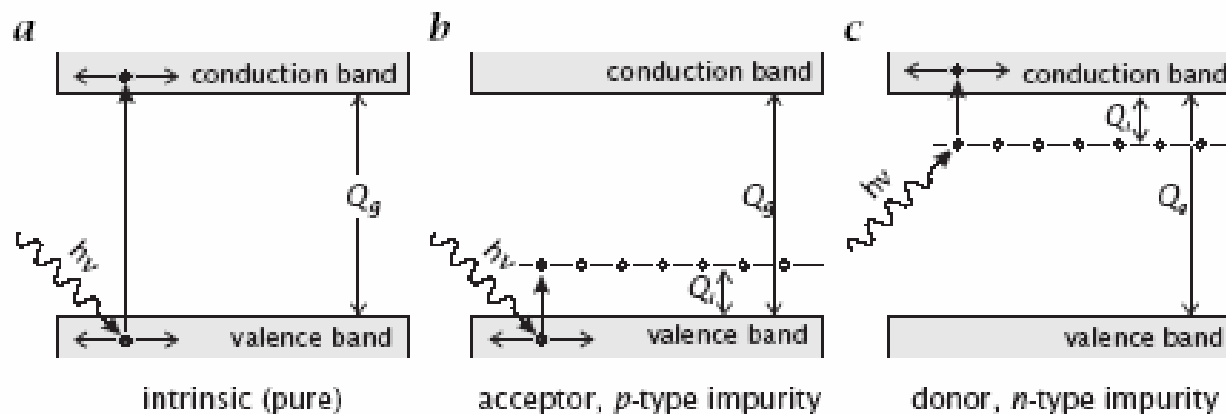


Figure 4.6: Energy-band diagrams for *a* intrinsic photoconductors; *b* extrinsic p-type photoconductors; and *c* extrinsic n-type photoconductors.

- c) photoresistivity (bolometers)
- d) photomechanical

Digital imaging

Charge Coupled Devices (CCDs)

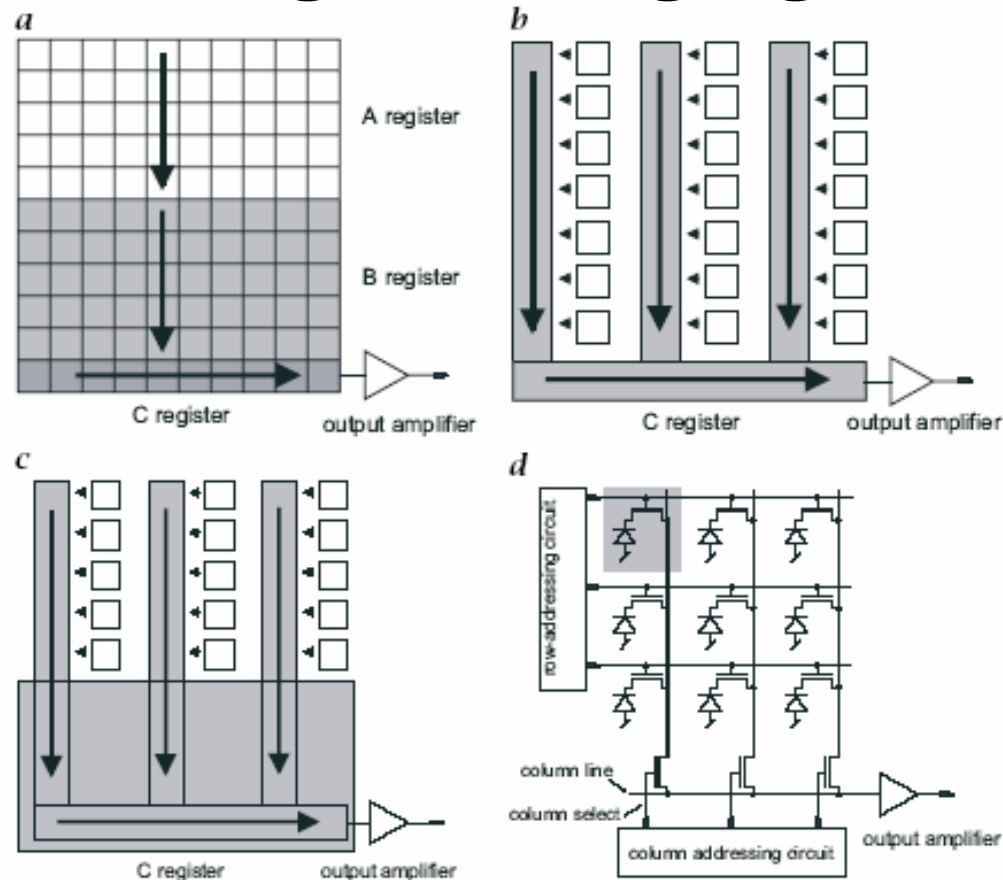
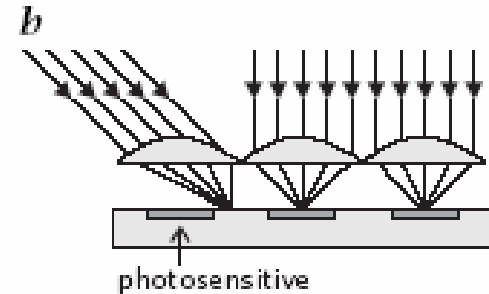
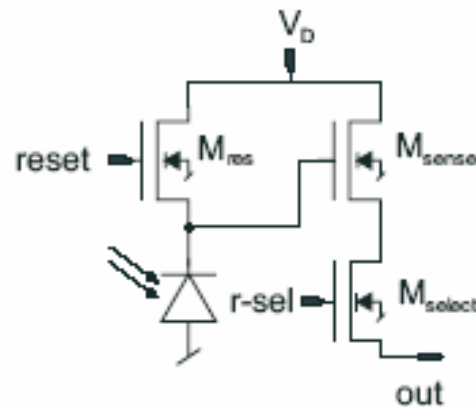


Figure 5.16: The four most important architectures of solid-state image sensors: a frame-transfer (FT) CCD with its three registers; b interline-transfer (IT) CCD with column light shields for vertical charge transfer; c field-interline-transfer (FIT) CCD, combining FT-CCD and IT-CCD principles for studio and broadcast applications; d traditional photodiode array image sensor with one photodiode and one selection transistor per pixel.

B. Jähne & H. Haußecker,
“Computer Vision and Applications,”
Academic Press 2000

Digital imaging

CMOS



microlens arrays improve
sensitivity

Figure 5.17: Schematic diagram of an APS pixel, consisting of a photodiode, a reset transistor, a sense transistor, and a row-select transistor. The active load transistor that completes the source-follower circuit is shared by all pixels in a column, and it is therefore needed only once per column.

APS=active pixel sensor

Color

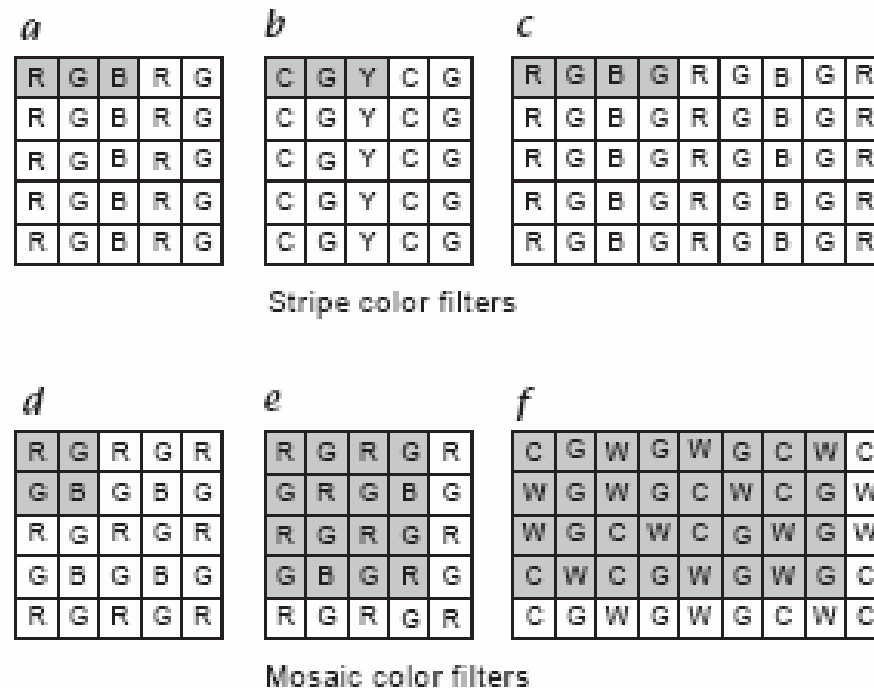
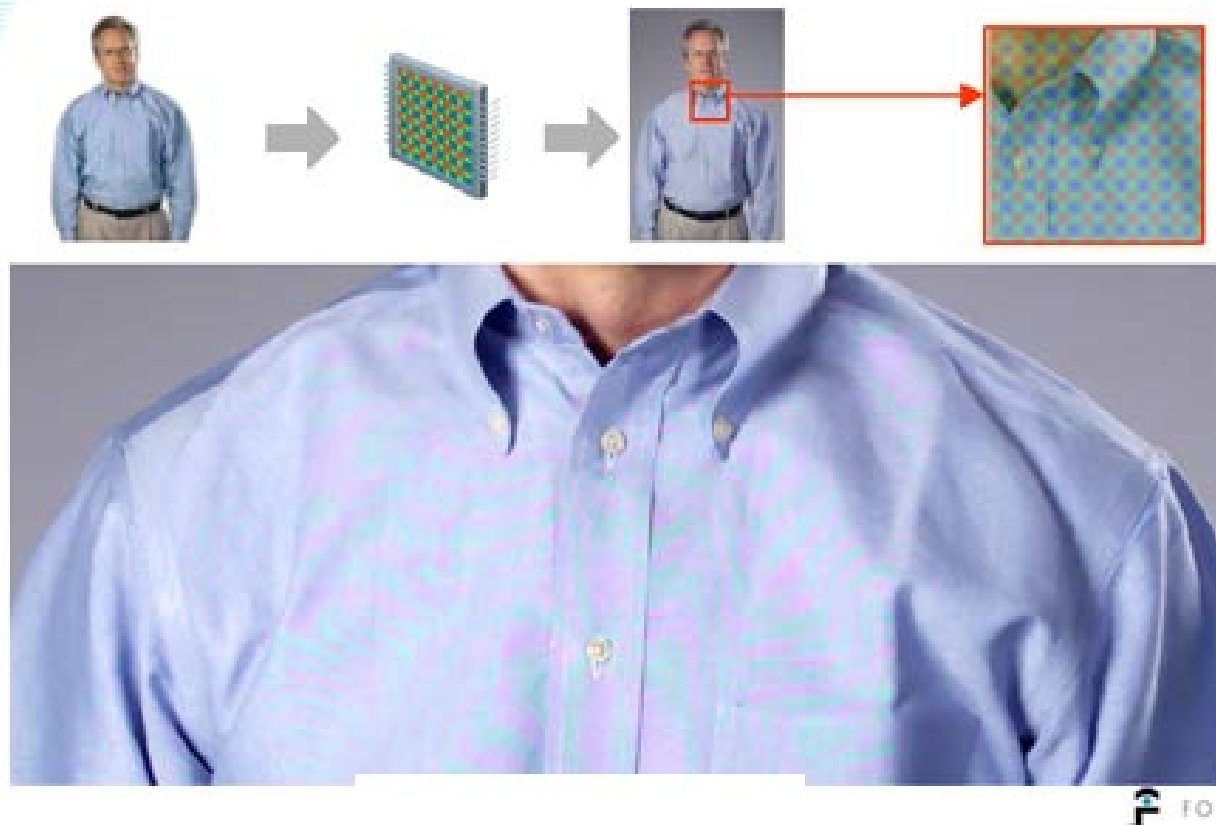


Figure 5.21: Illustration of different color filter types for single-chip color sensors. The unit cell (basic arrangement of color filter patches that is periodically repeated on the image sensor) is shown as shaded rectangle: a primary color (RGB) stripe filter with 3×1 unit cell; b complementary color (CGY) stripe filter with 3×1 unit cell; c primary color (RGB) stripe filter with 4×1 unit cell; d Bayer color mosaic filter with 2×2 unit cell; e Bayer color mosaic filter with 4×4 unit cell; f shift-8 color mosaic filter using complementary colors in an 8×4 unit cell.

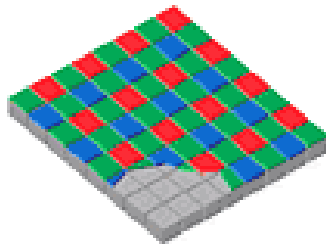
Color

Mosaic Filter: Image Quality

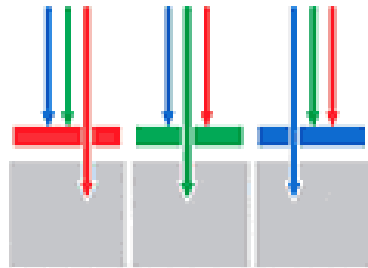


Improved color: the Foveon

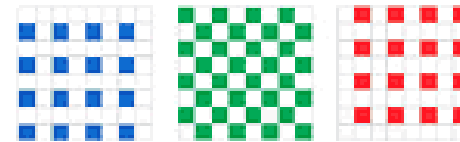
Mosaic Capture



In conventional systems, color filters are applied to a single layer of photodetectors in a tiled mosaic pattern.

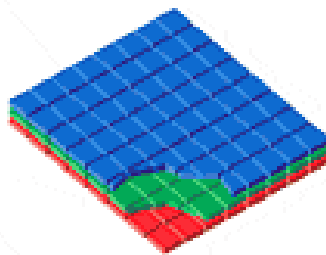


The filters let only one wavelength of light - red, green or blue - pass through to any given pixel, allowing it to record only one color.

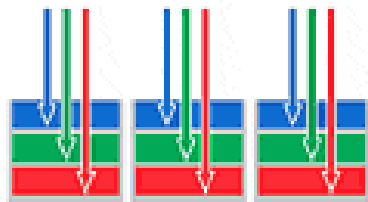


As a result, mosaic sensors capture only 25% of the red and blue light, and just 50% of the green.

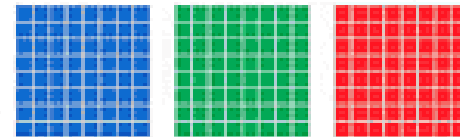
Foveon® X3™ Capture



A Foveon® X3™ image sensor features three separate layers of photodetectors embedded in silicon.

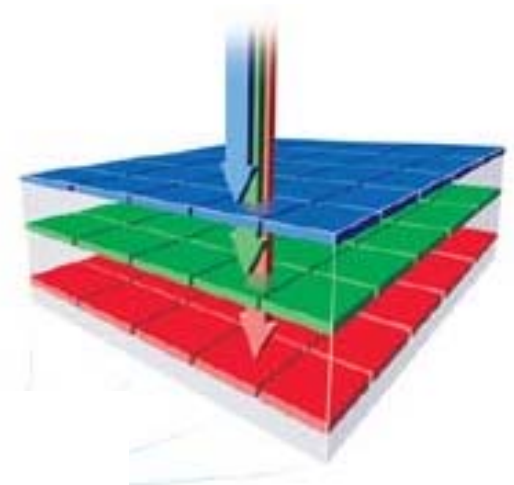
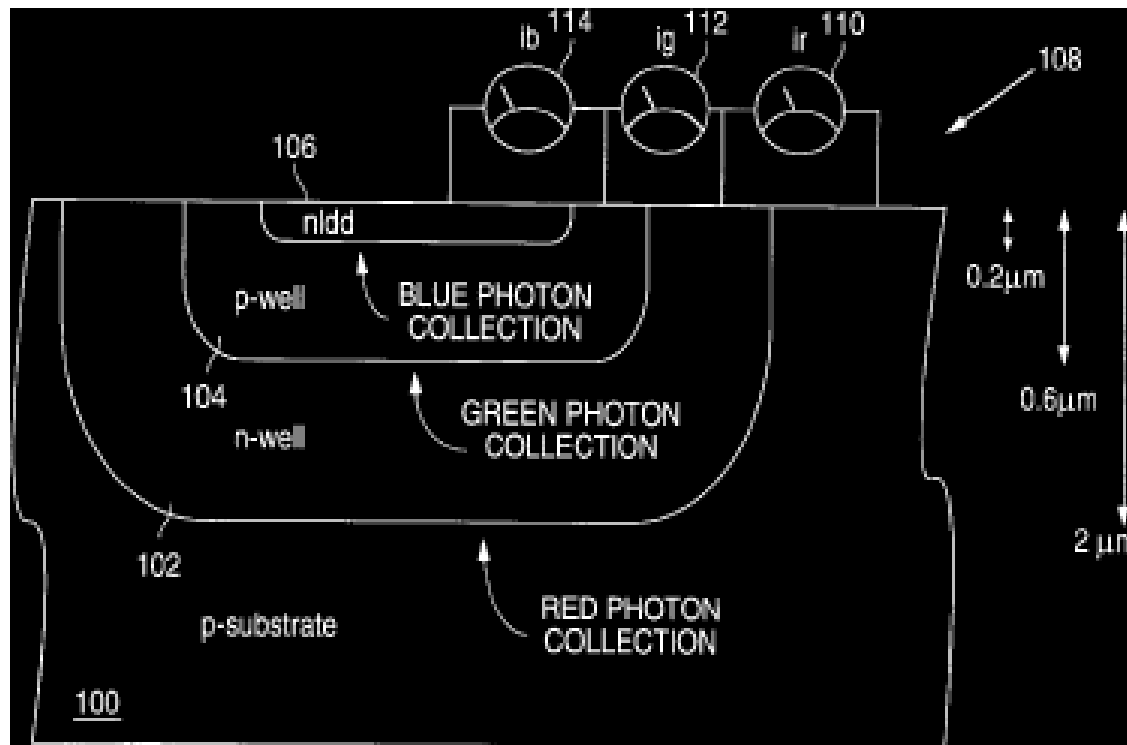


Since silicon absorbs different colors of light at different depths, each layer captures a different color. Stacked together, they create full-color pixels.



As a result, only Foveon X3 image sensors capture red, green and blue light at every pixel location.

Improved color: the Foveon



US Patent 5,965,875

Improved color: the Foveon

Quality Benefits of Foveon X3™

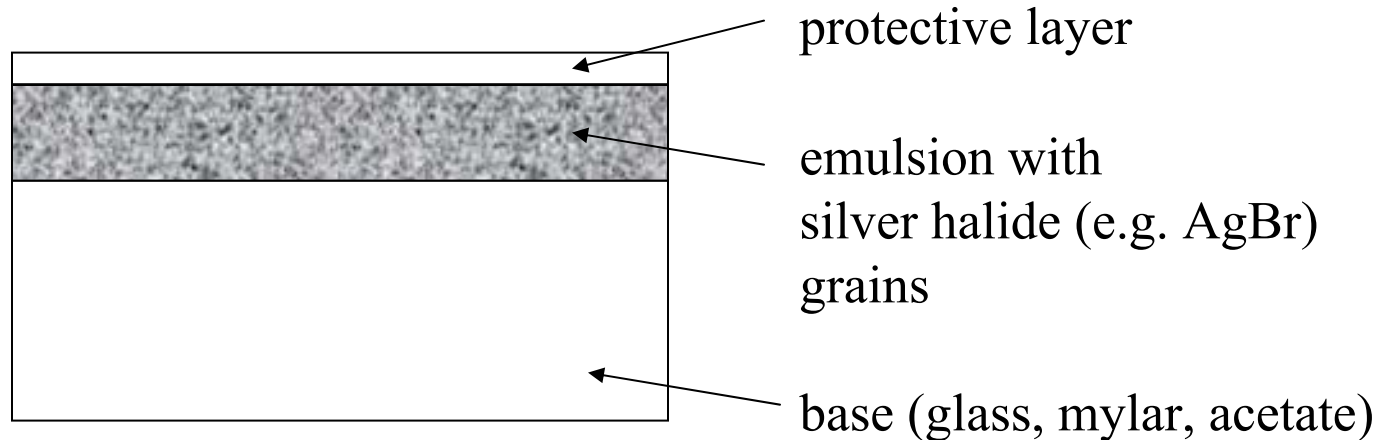
Mosaic Filter

Foveon X3™



Light modulation

Photographic films / plates



Exposure: $\text{Ag}^+ + \text{e}^- \rightarrow \text{Ag}$ (or $2\text{Ag}^+ + 2\text{e}^- \rightarrow \text{Ag}_2$)

Collection of development specks = **latent image**

development speck

Development (1st chemical bath): converts specks to metallic silver

Fixing the emulsion (2nd chemical bath): removal of unexposed silver halide

Photographic film / plates

- Exposure (energy) : energy incident per unit area on a photographic emulsion during the exposure process (units: mJ/cm²)

$$\text{Exposure} = \text{incident intensity} \times \text{exposure time} \quad E = I_{\text{expose}} \times T$$

- Intensity transmittance : average ratio of intensity transmitted over intensity incident after development

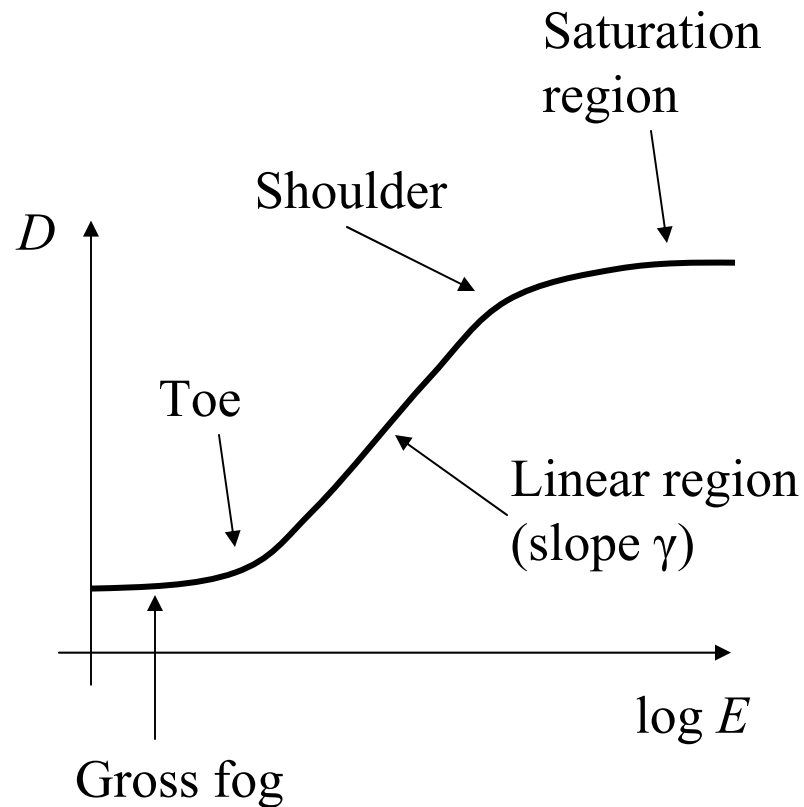
$$\tau(x, y) = \frac{\text{local}}{\text{average}} \left\{ \frac{I \text{ transmitted at } x, y}{I \text{ incident at } x, y} \right\}$$

- Photographic density

$$D = \log_{10} \left(\frac{1}{\tau} \right) \quad \Leftrightarrow \quad \tau = 10^{-D}$$

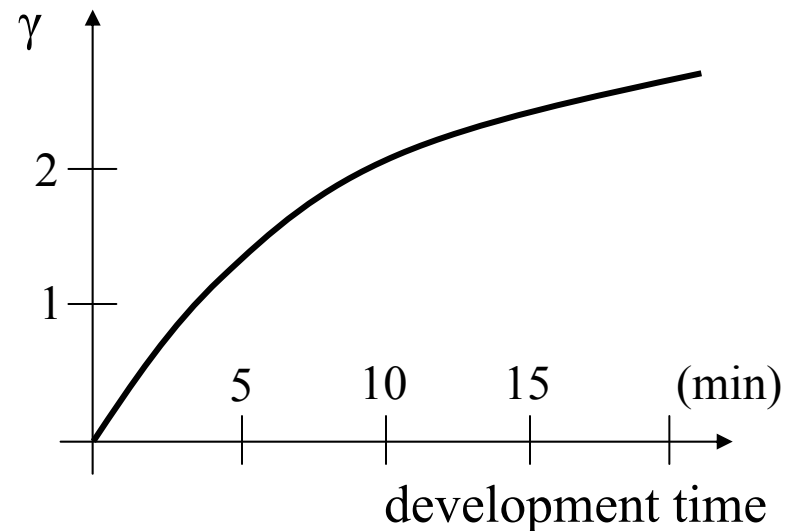
Photographic film / plates

- Hurter-Driffield curve

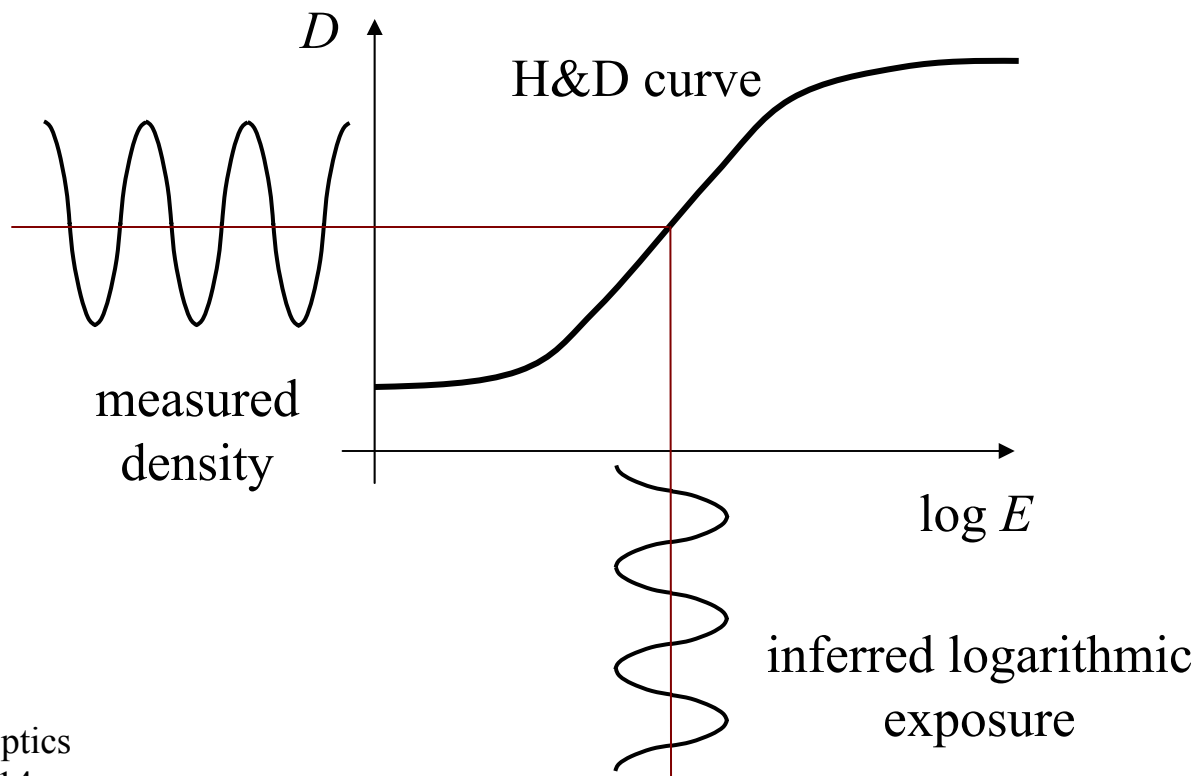
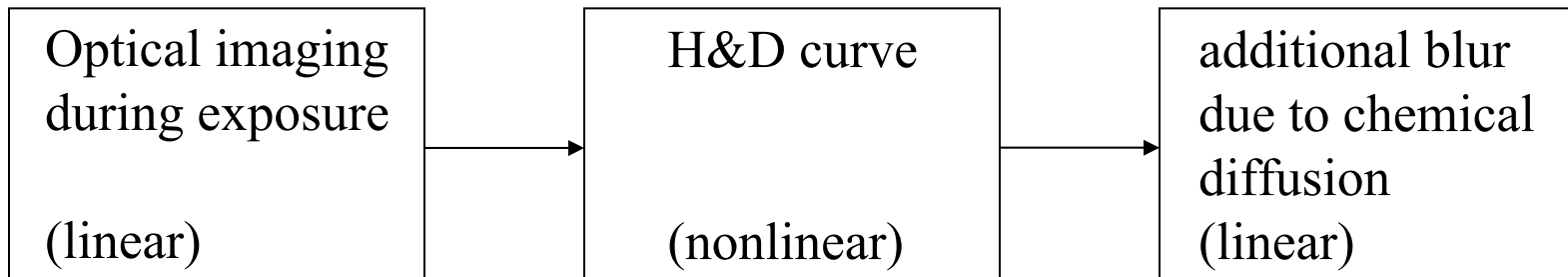


- Gamma curve

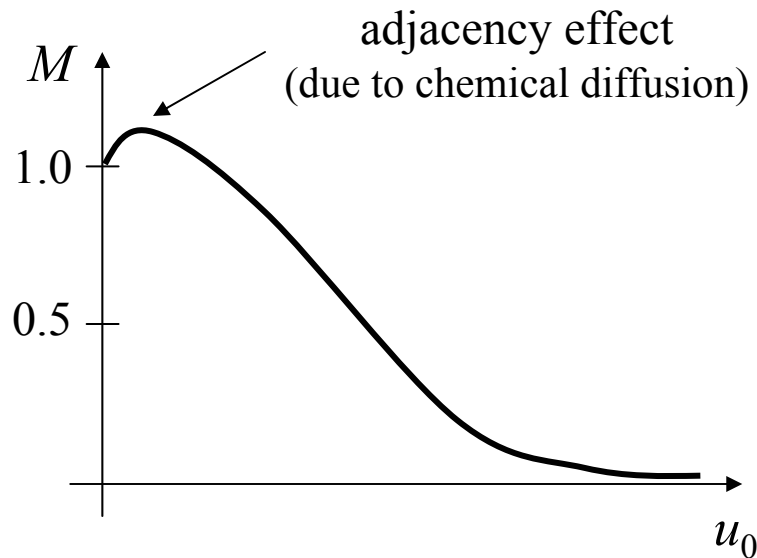
γ high/low : high/low
contrast film



Kelley model of photographic process



The Modulation Transfer Function



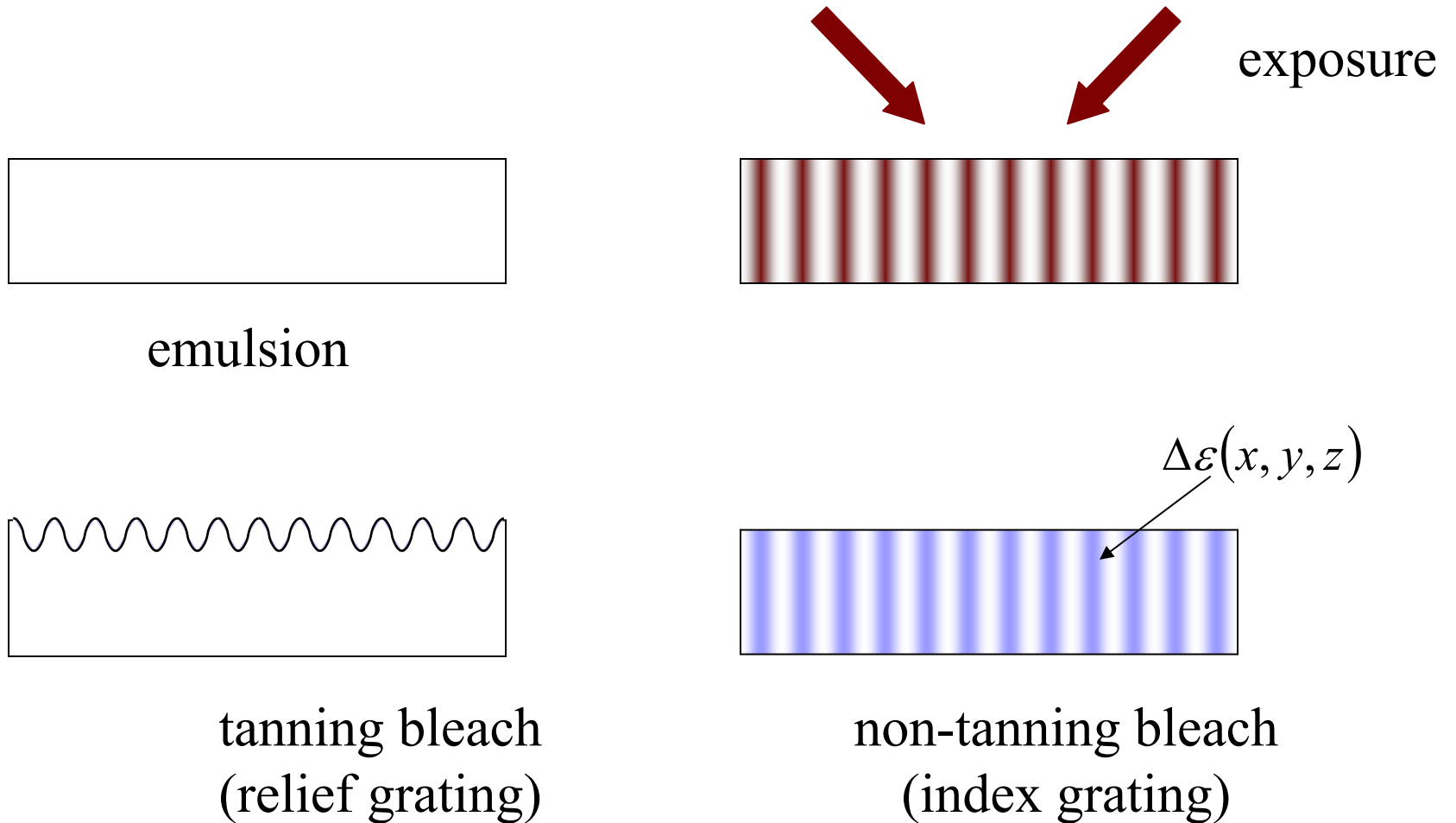
Exposure:

$$E = E_0 + E_1 \cos 2\pi u_0 x$$

“Effective exposure”:

$$E' = E_0 + M(u_0)E_1 \cos 2\pi u_0 x$$

Bleaching / phase modulation

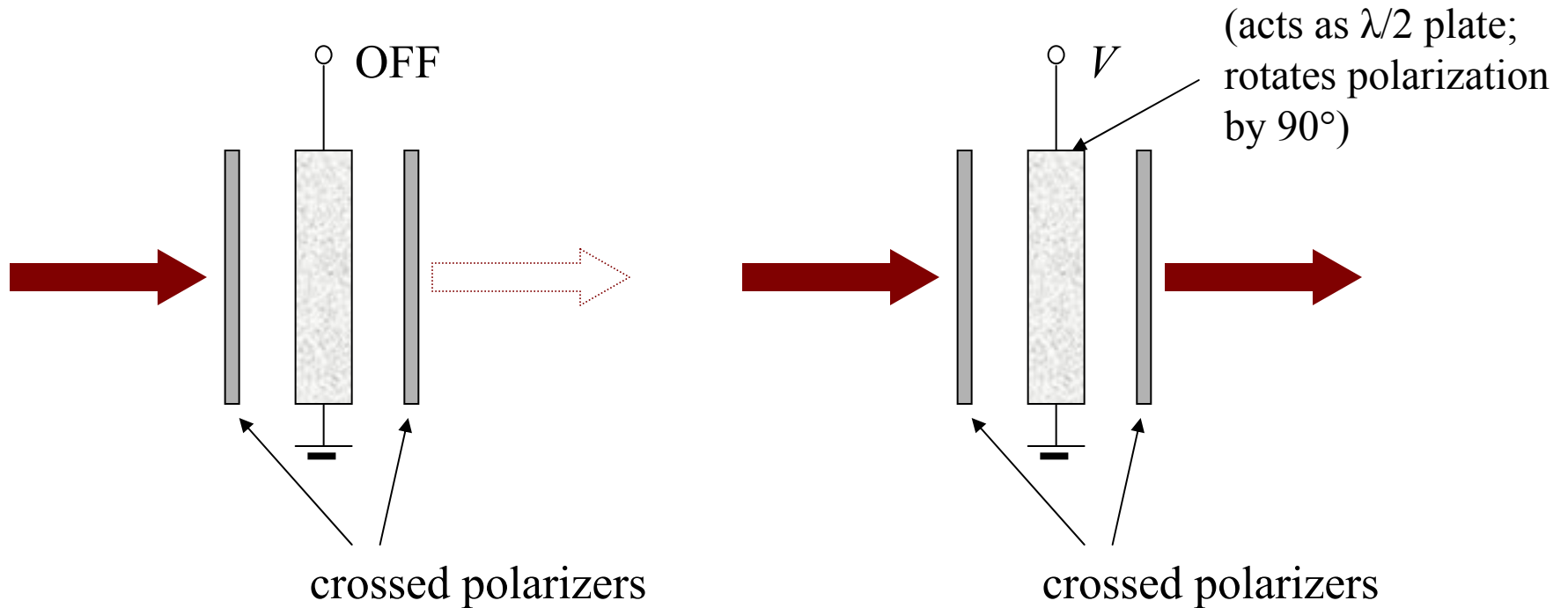


Spatial Light Modulators

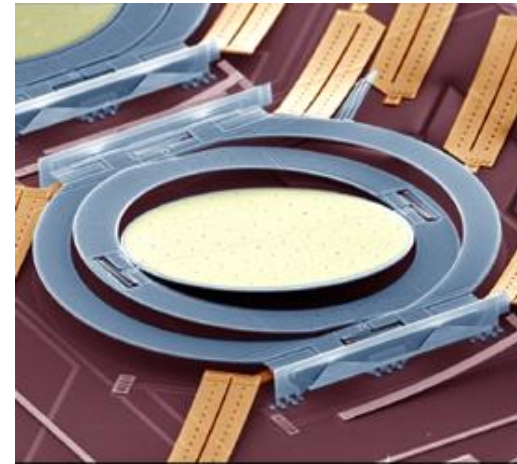
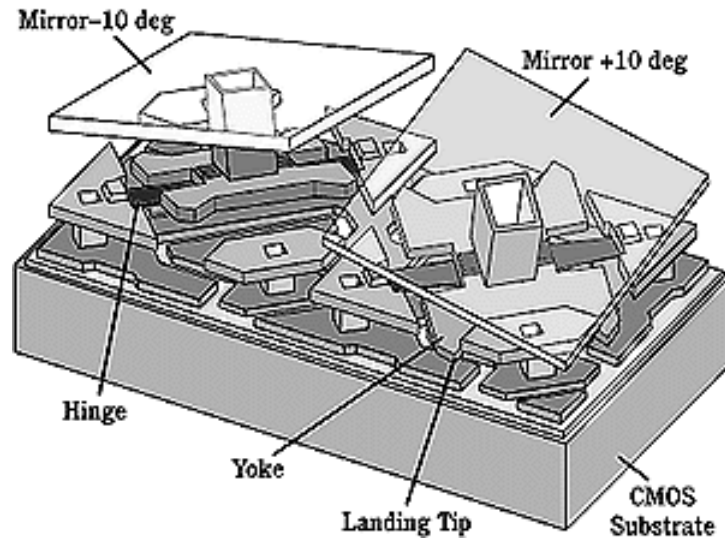
- Liquid crystals
- Magneto-Optic
- Micro-mirror
- Grating Light Valve
- Multiple Quantum Well
- Acousto-Optic

Liquid crystal modulators

- Nematic
- Smectic (smectic-C* phase: ferroelectric)
- Cholesteric



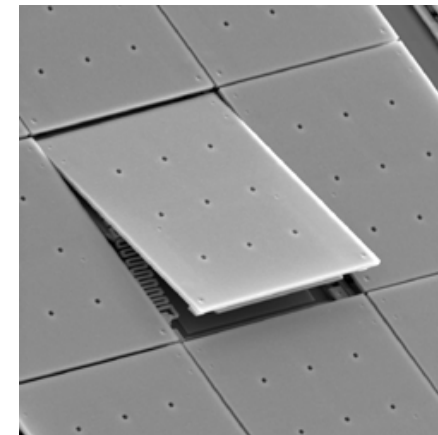
Micro-mirror technology



Lucent (Bell Labs)

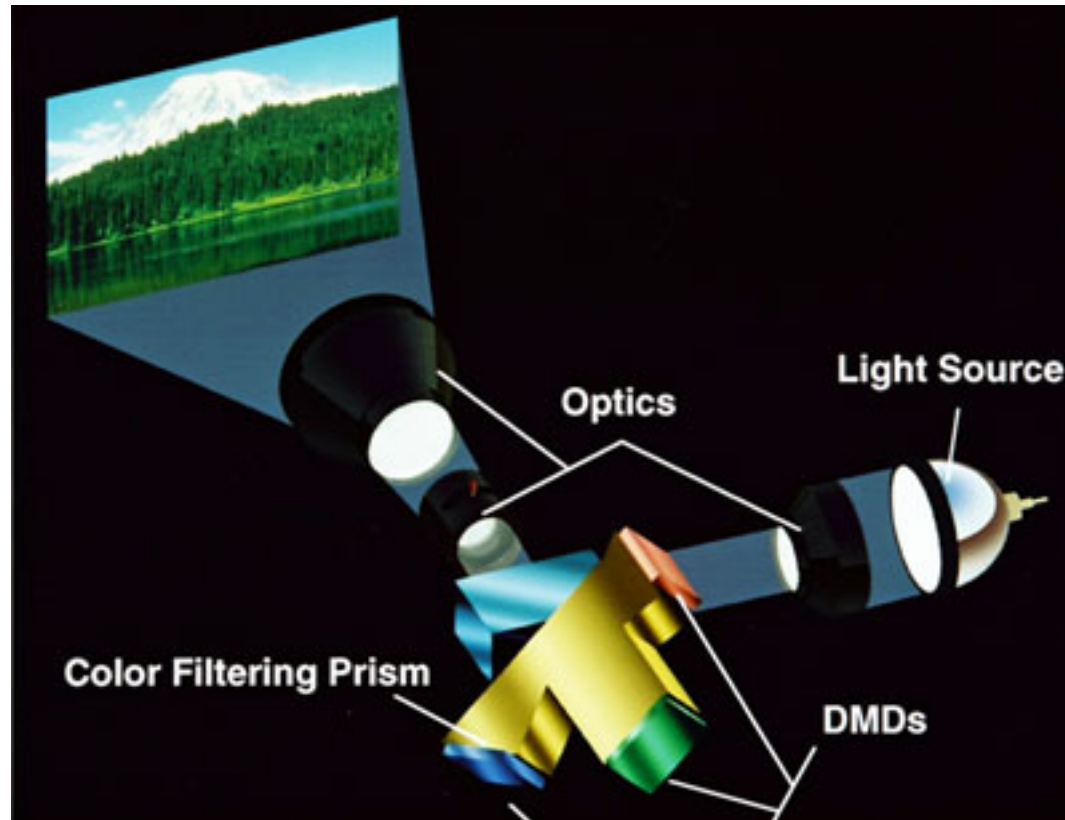


Texas Instruments DMD/DLP



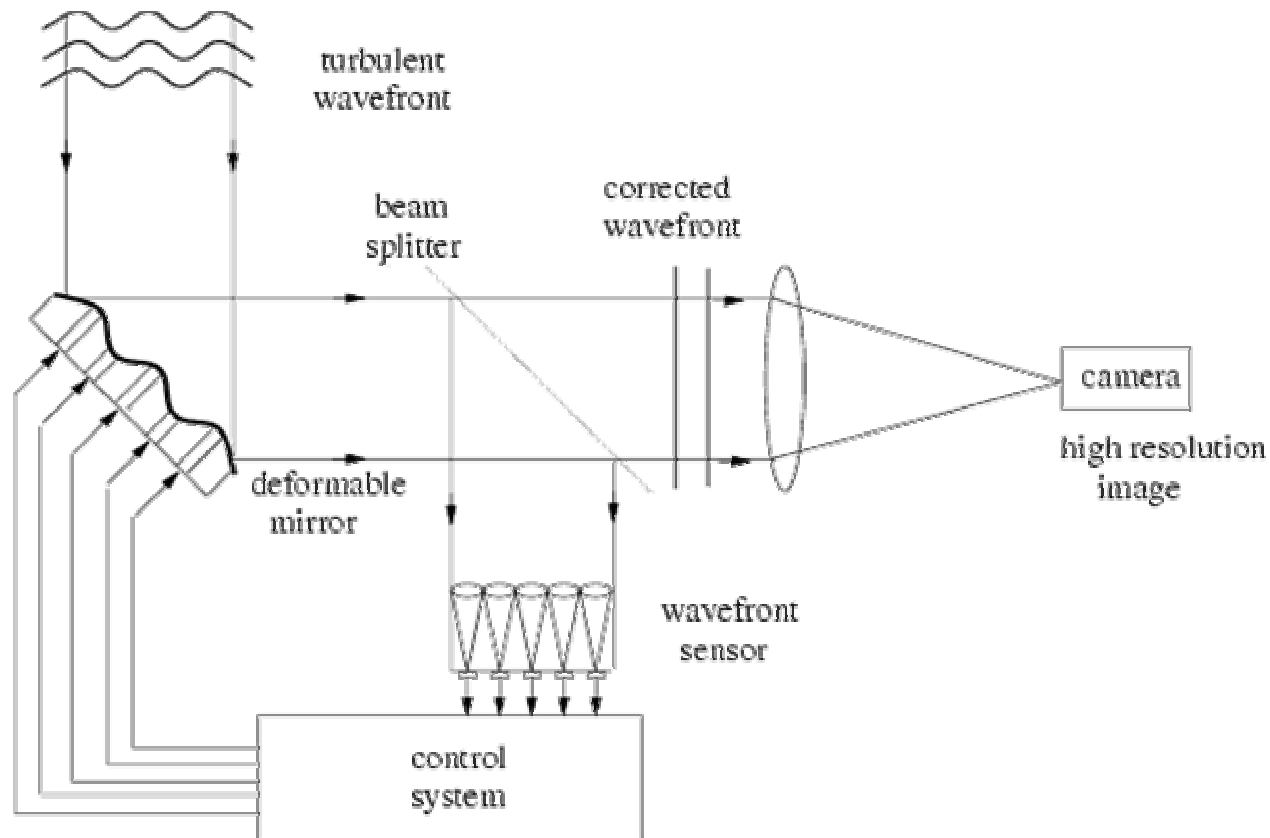
Sandia

Micro-mirror display

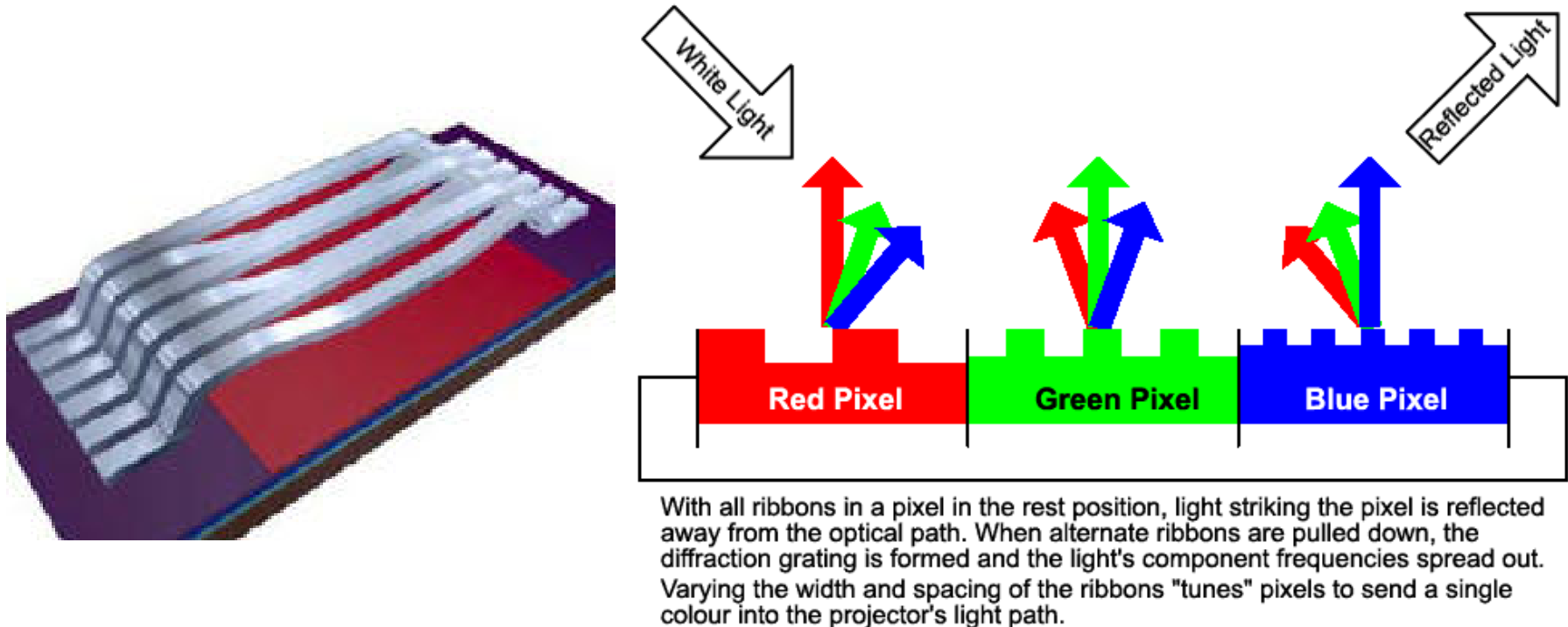


<http://www.howstuffworks.com>

Micromirrors for adaptive optics



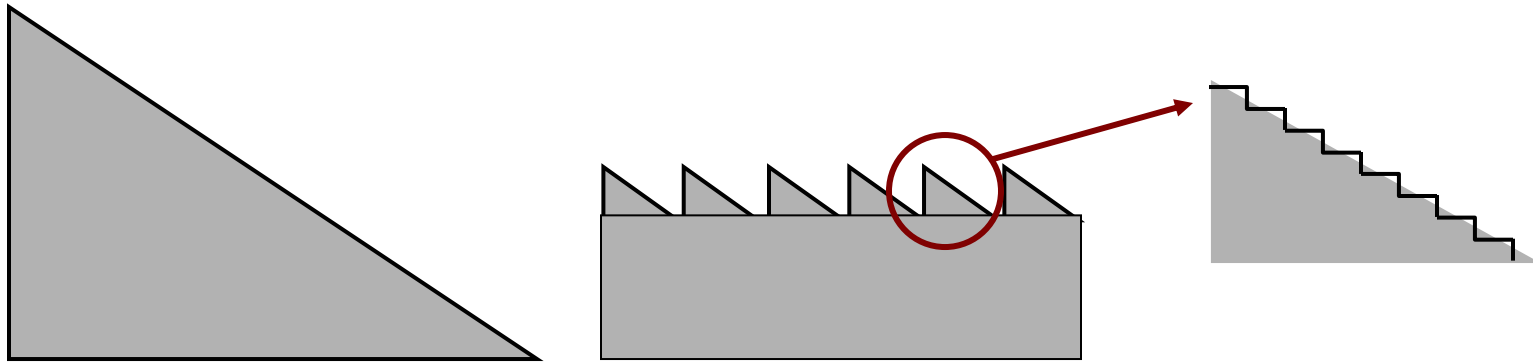
Grating Light Valve (GLV) display



www.meko.co.uk

Silicon Light Machines, www.siliconlight.com

Binary Optics



Refractive
(prism)

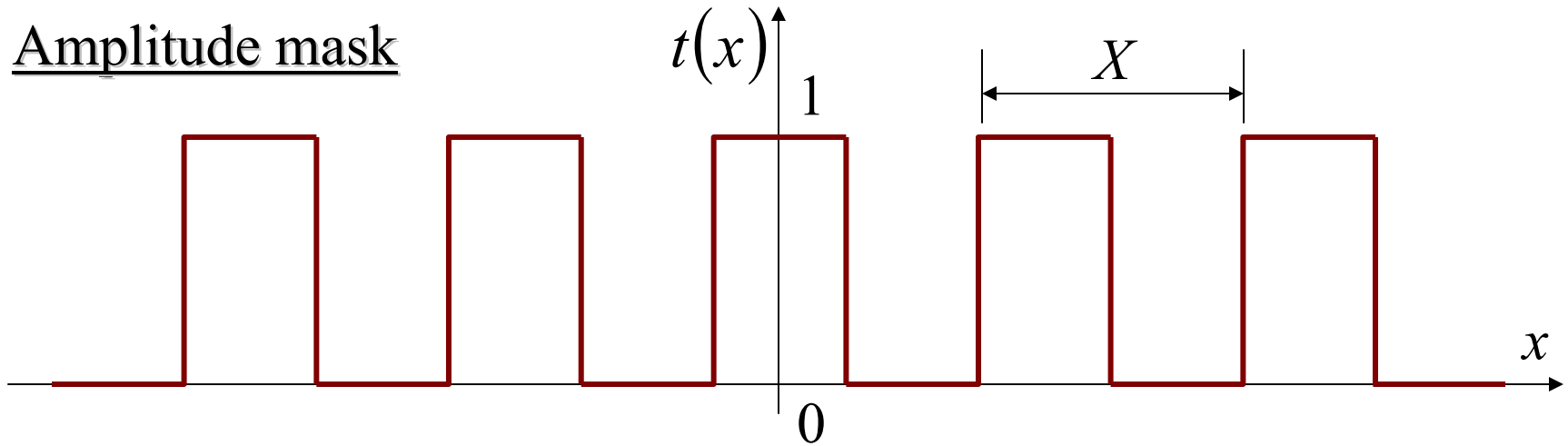
Diffractive
(blazed grating)

Binary

$$\eta_1 = \text{sinc}^2\left(\frac{1}{2^N}\right)$$

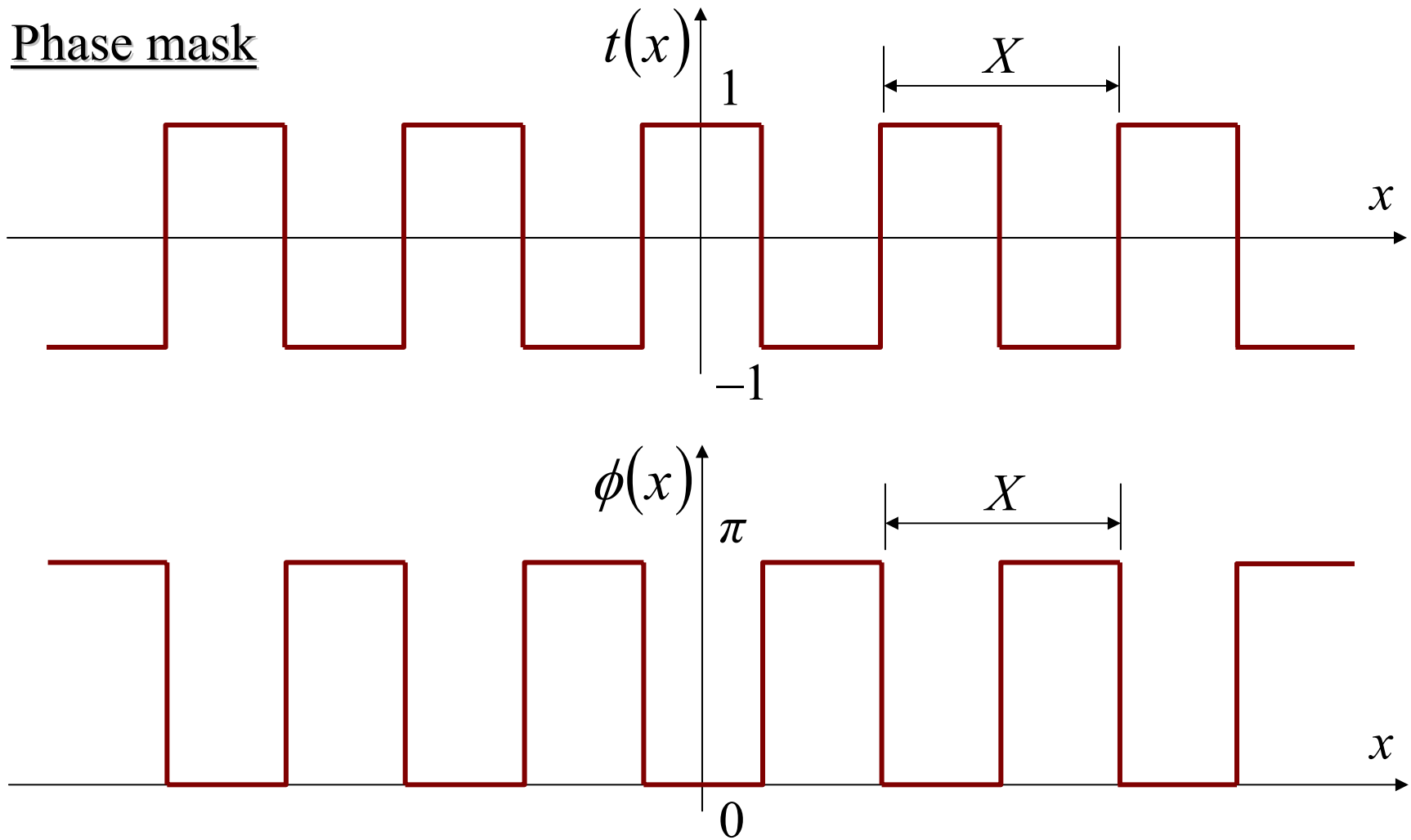
efficiency of 1st diffracted order from
step-wise (binary) approximation to
blazed grating with N steps over 2π range

Binary Optics: binary grating



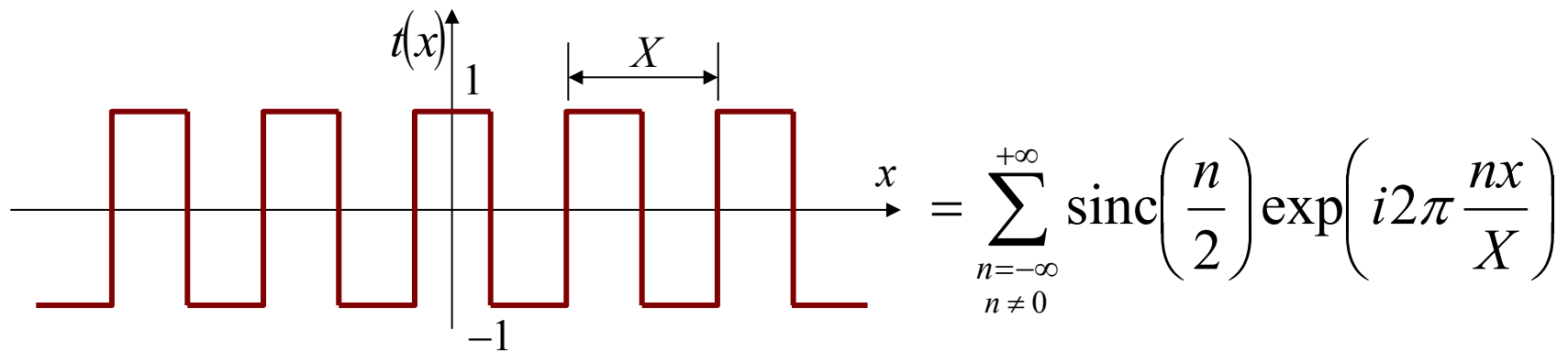
Binary Optics: binary grating

Phase mask

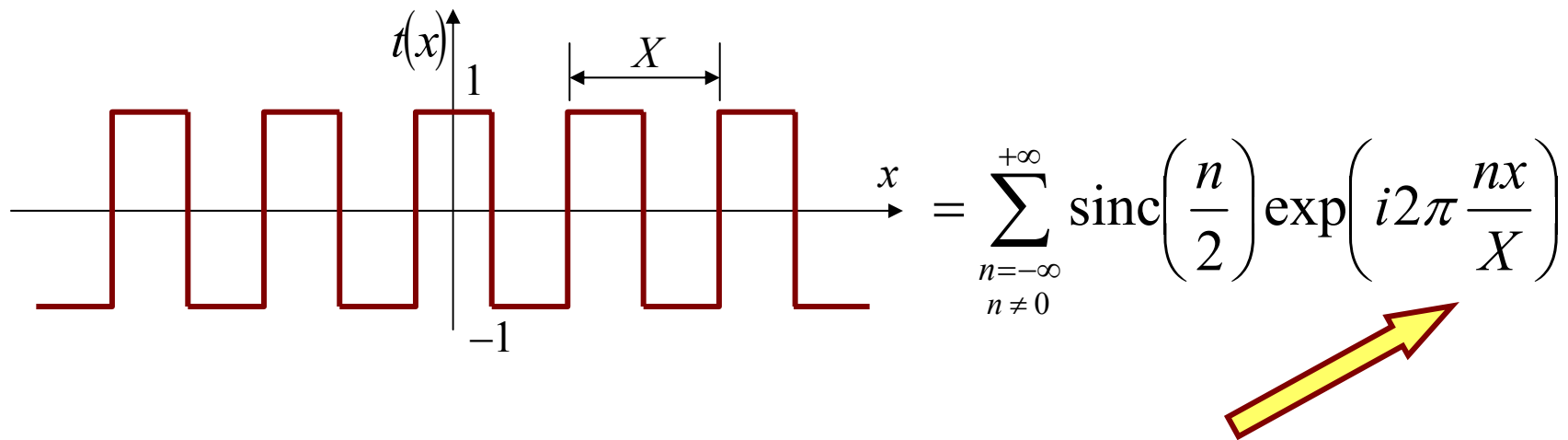


$$t(x) = \exp[i \phi(x)]$$

Fourier series for binary phase grating



Fourier series for binary phase grating



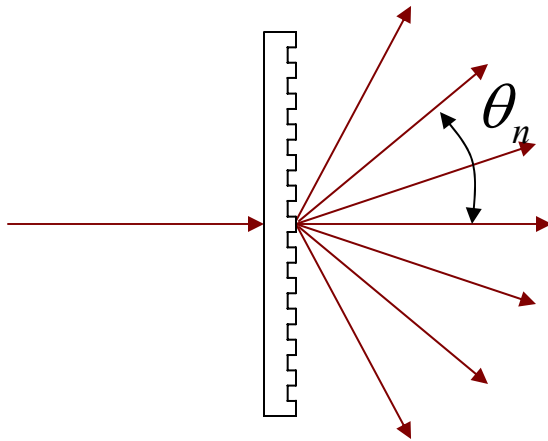
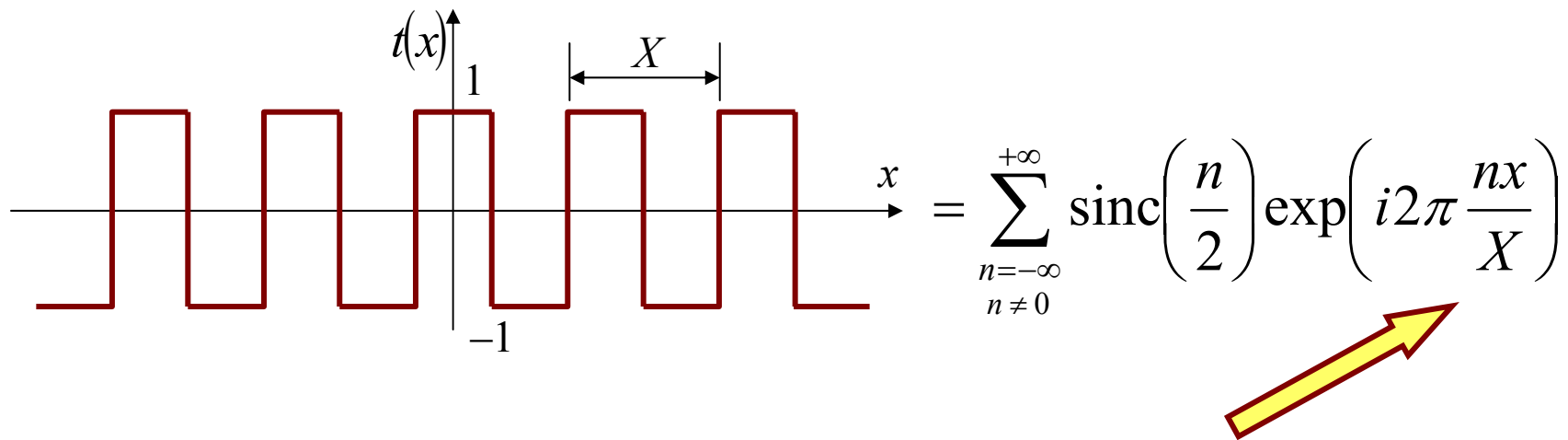
identify physical meaning:

- plane waves
- orientation of n^{th} plane wave:

$$\sin \theta_n = n\lambda / X$$

- ***diffracted orders***

Fourier series for binary phase grating



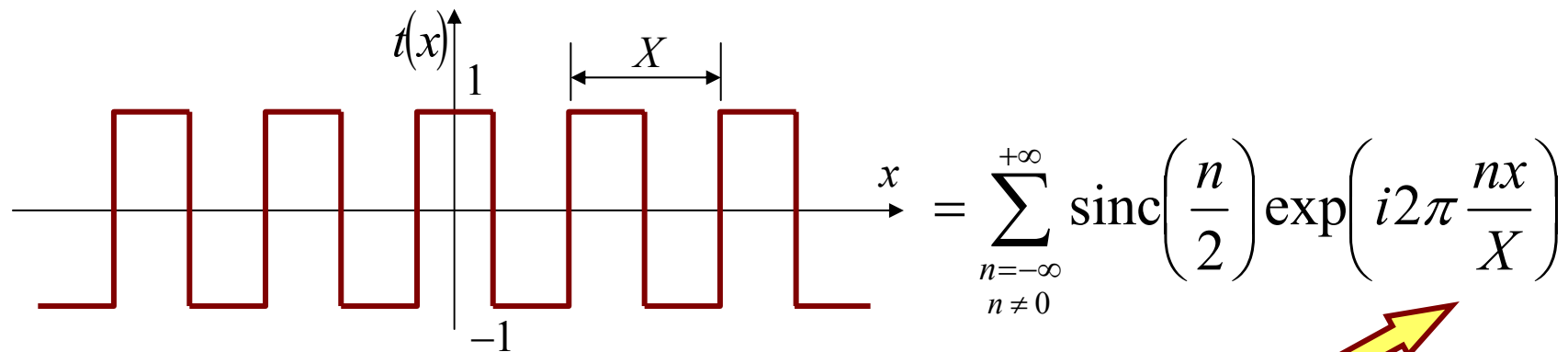
identify physical meaning:

- plane waves
- orientation of n^{th} plane wave:

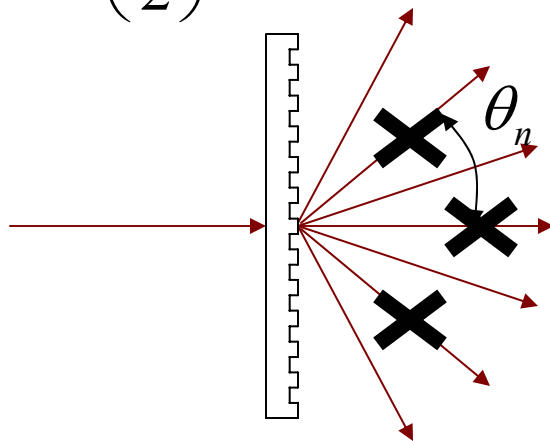
$$\sin \theta_n = n\lambda / X$$

- ***diffracted orders***

Fourier series for binary phase grating



$\text{sinc}\left(\frac{n}{2}\right) \Rightarrow$ odd orders only!



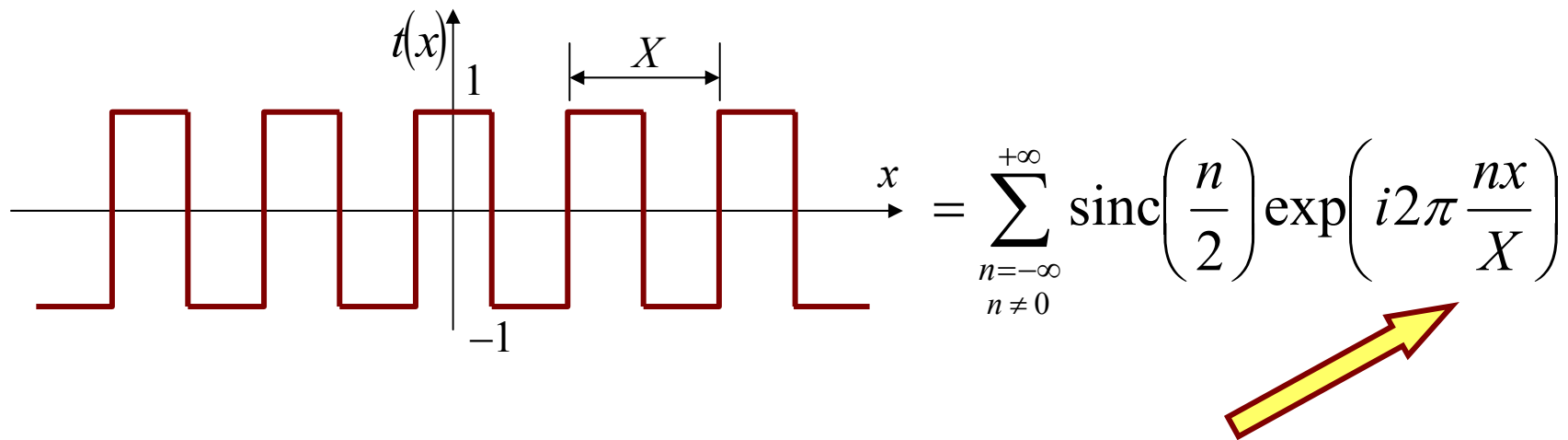
identify physical meaning:

- plane waves
- orientation of n^{th} plane wave:

$$\sin \theta_n = n\lambda / X$$

- ***diffracted orders***

Fourier series for binary phase grating



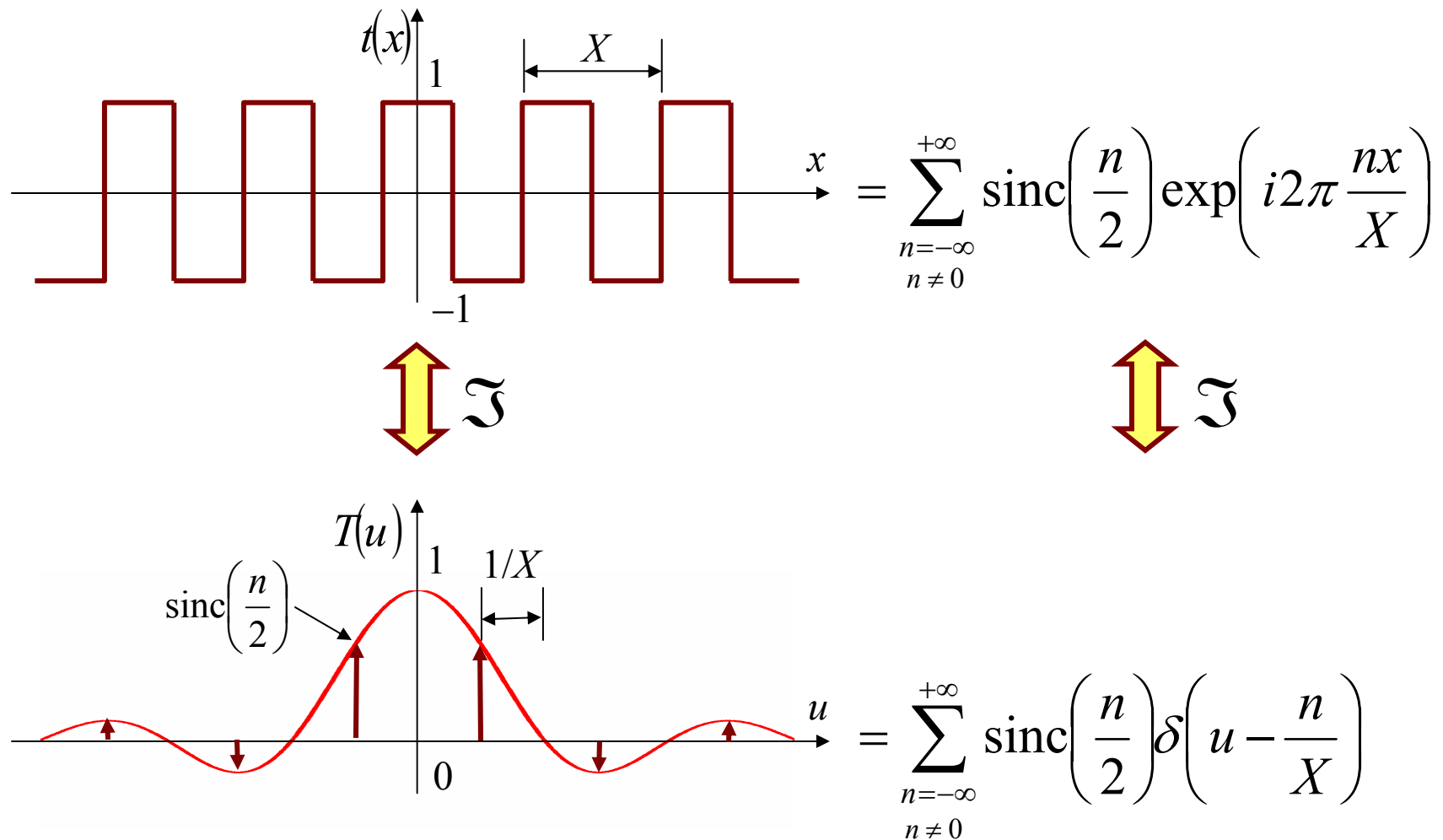
Fourier transform:

- $\exp(i2\pi u_0 x) \leftrightarrow \delta(u - u_0)$

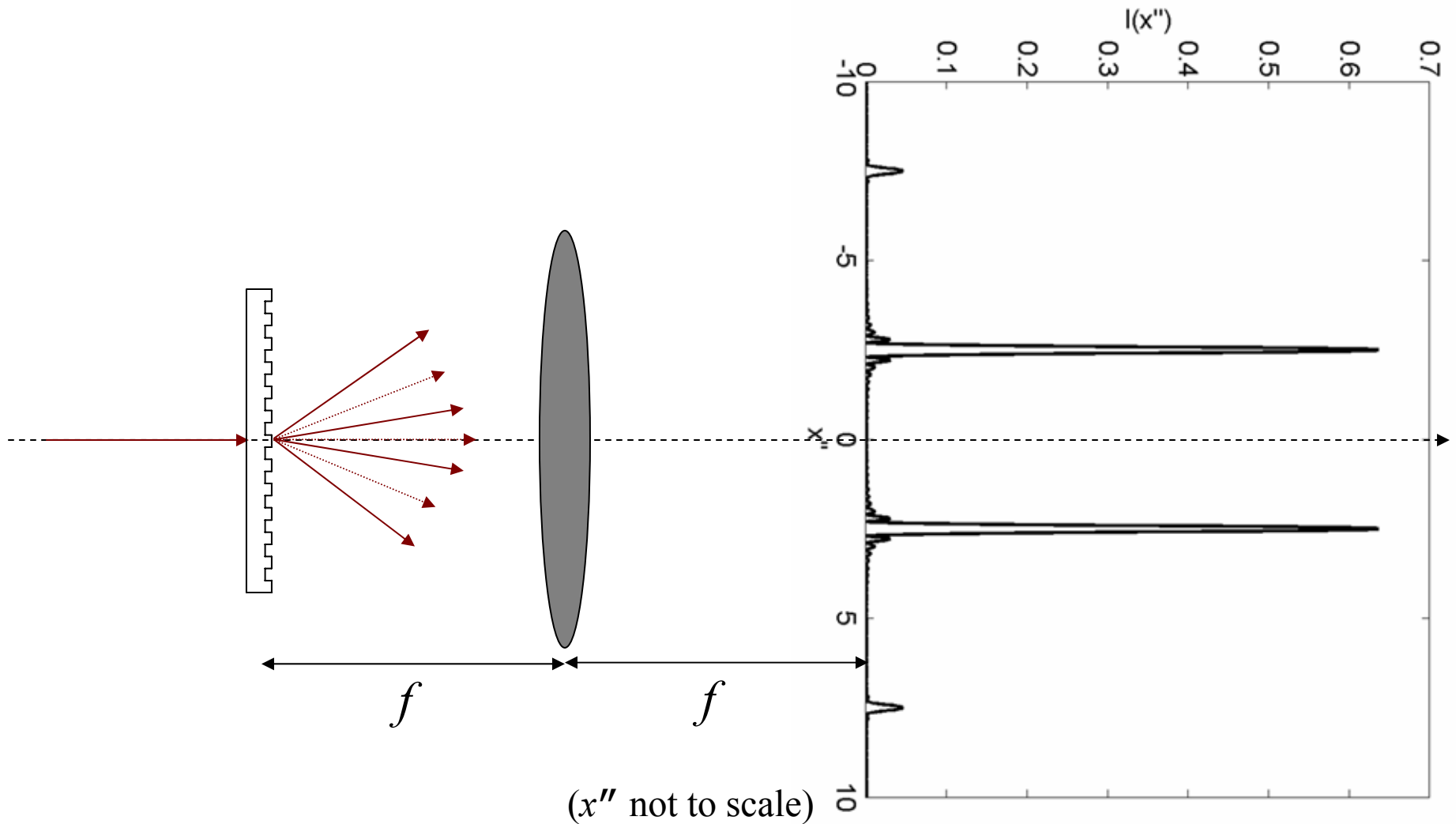
- result is

$$\sum_{\substack{n=-\infty \\ n \neq 0}}^{+\infty} \text{sinc}\left(\frac{n}{2}\right) \delta\left(u - \frac{n}{X}\right) \quad (\text{Fourier series})$$

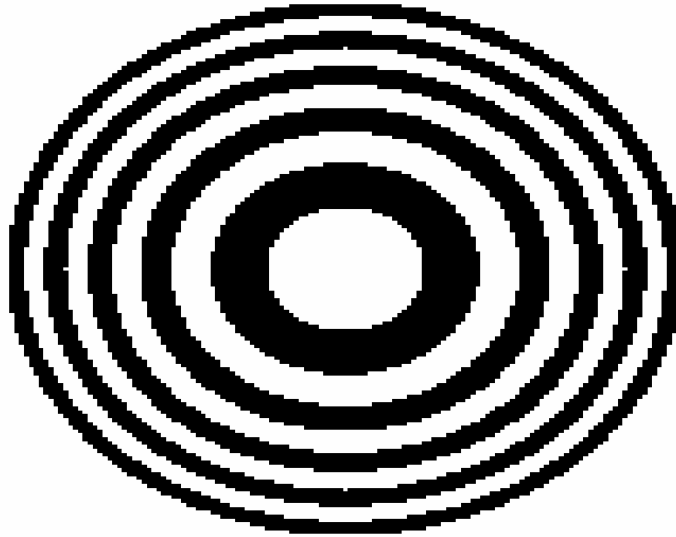
Diffracted spectrum from binary phase grating



Fourier-plane diffraction from finite binary phase grating



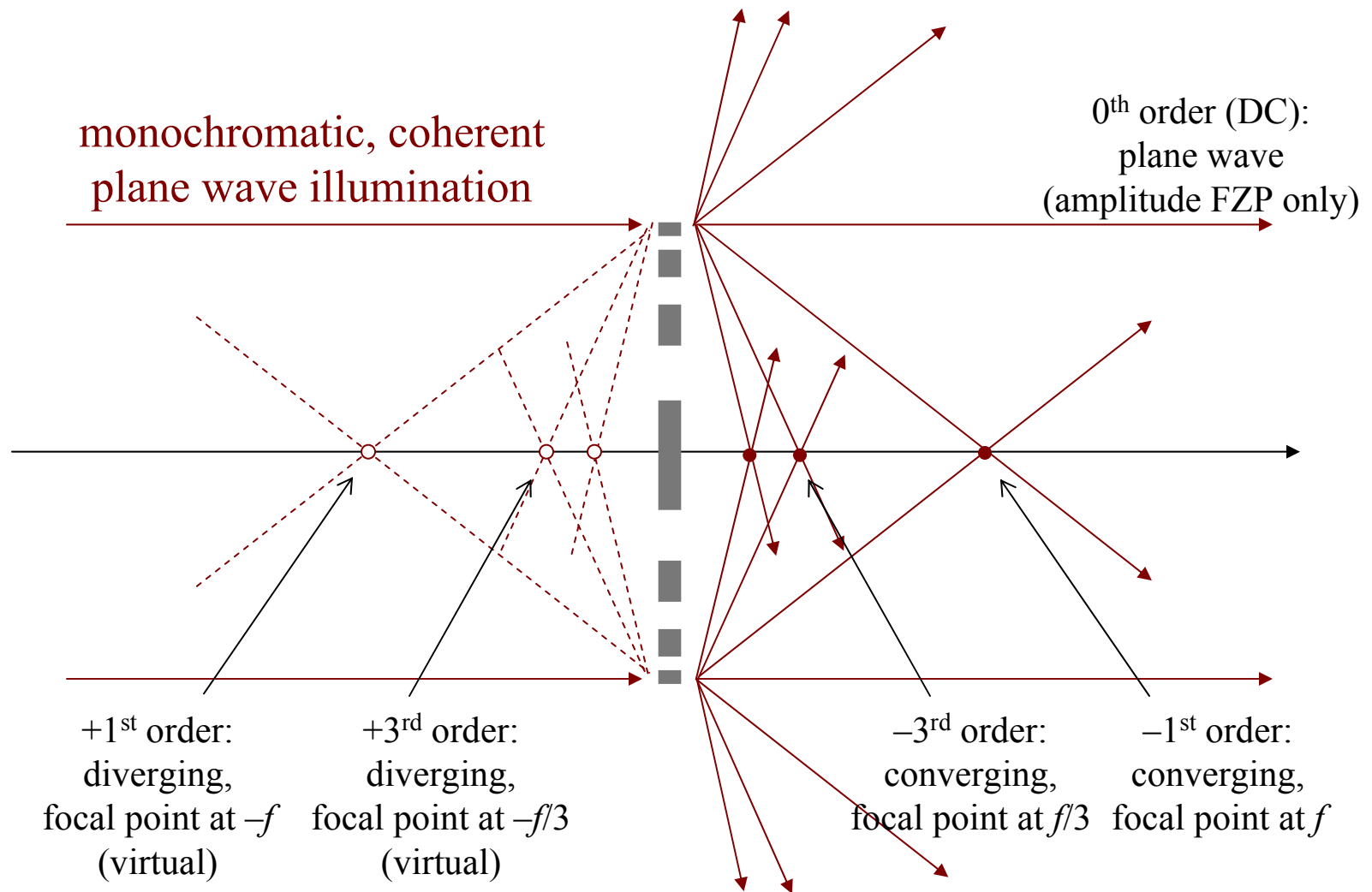
The Fresnel Zone Plate (FZP)



amplitude FZP: $g(x, y) = \frac{1}{2} \left[1 + \text{sgn} \left(\cos \left(\pi \frac{r^2}{\lambda f} \right) \right) \right]$ $r = \sqrt{x^2 + y^2}$

phase FZP: $g(x, y) = \text{sgn} \left(\cos \left(\pi \frac{r^2}{\lambda f} \right) \right)$

Field diffracted from the FZP



FZP relationships

$$r_m = \sqrt{\frac{m\lambda f}{2}} \quad m^{\text{th}} \text{ zone radius}$$

$$\delta_m \equiv r_m - r_{m-2} \approx \sqrt{\frac{\lambda f}{2m}} \quad m^{\text{th}} \text{ zone width}$$

